SD-POWER LED Series

Technical Datasheet for SD-03/04

Features

SD-Power series is desingned for high current operation and high flux output applications. SD-Power LED its thermal management perform exceeds then other power LED solutions. It integrate of the art SND design and thermal emission material. SD-Power LED is ideal light sources for general applications, custom designed solutions, and automotive large LCD backlights.

high Luminance *Super high Flux output and

*Designed for high current operation

*Low thermal resistance

*SMT solder bility

*Lead Free product

*ROHS compliant

Applications

*General Illumination

- Outdoor & Indoor

architectural lighting

- Decorative lighting

- Torch lighting

- Portable lighting

and Reading lighting

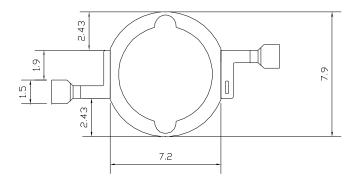
- Traffic signaling

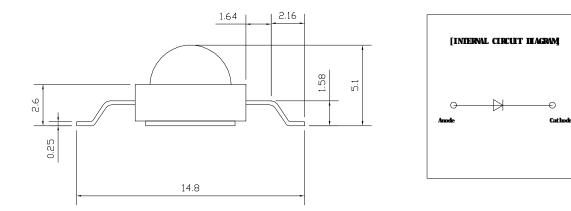
Full Code of SD-Power LED Series

Full code form:	<u>SD</u>	-	<u>P</u>	<u>XX</u>	<u>XX</u>	<u>X</u>	<u>X</u>	<u>X</u>	<u>X</u>	<u>XX</u>
	1		2	3	4	5	6	7	8	9
Part Number										
1- SD: SnowDragon										
2- P : High Power	LED									
3- XX: Size										
80 - 0 8	m									
4- XX: Emitted Co	olor									
R1 - Re c	625 n	m	B3 -	Blue	465nm	W3	3 - Wa	rm W	hite 2	2700-3300K
5-X:Wafer Size										
2 - 24mi	I	3 -	30mi	I	4 - 40	mi I	6	- 60m	i I	
6- X : Wafer Quan	tity									
1 - 1EA		4 -	4EA							
7-X:Viewing Ang	gle									
0 - 120d	eg	1 -	15de g]						
8-X:Power										
0 - 0.5W		1 -	1W		3 - 3W					
9- XX: Brightness	Grade	9								
40 - 40-	501 m		70 - 7	70-801	m					

Outline Dimensions

1、Dome Type





Notes

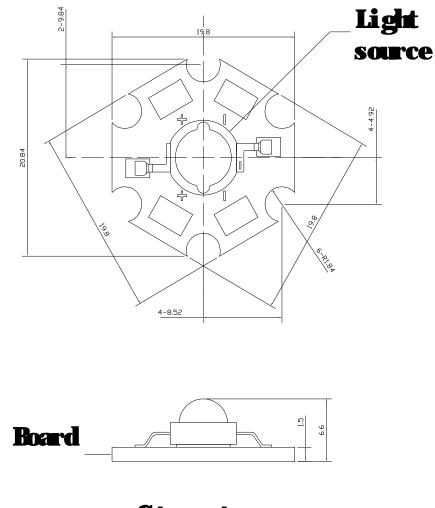
1. All dimensions are in millimeters.(tolerance:±0.2)

2. Scale:none

*the appearance and specifications of the product may be changed for improvment without notice.

Outline Dimensions

2、Dome Type





Notes

1. All dimensions are in millimeters.(tolerance:±0.2)

2. Scale:none

*the appearance and specifications of the product may be changed for improvment without notice.

1、Cool -White

Parameter	Symbol	Value			Unit
	29	Min	Тур	Max	Umt
Luminous Flux [1]	↓ V ^[2]	50	~	130	lm
Correlated Color Temperature ^[3]	CCT	4500	~	10000	K
Forward Voltage [4]	VF	3.0	~	3.8	V
View Angle	201/2	120			deg.
Thermal Resistance ^[5]	Rθ ј-в	8			°C/W
Thermal Resistance ^[6]	R θ j-c	6.5		°C/W	

1-1 Electrical-Optical Characteristics at IF=350mA, TA=25 $^\circ\!\!\mathbb{C}$

1-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	IF	350	mA
Power Dissipation	Pd	1.05~1.33	W
Junction Temperature	Tj	125	°C
Operating Temperature	Topr	-30~+85	°C
Storage Temperature	Tstg	-40~+120	°C
ESD Sensitivity [7]	~	±2,000V HBM	~

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] $\phi \mathbf{v}$ is the total luminous flux output as measured with an integrated sphere.
- [3] Correlated Color Temperatures is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ testing tolerance
- [4] A tolerance of $\pm 0.06V$ on forward voltage measurements
- [5],[6] R θ J-B is measured with a SSC metal core pcb.(25°C \leq TJ \leq 110°C)
 - R θ J-C is measured with only emitter.. (25°C \leq TJ \leq 110°C)

Break voltage of Metal PCB is 6.5kVAC

[7]It is included the zener chip to protect the product from ESD.

-----Caution-----

2. Neutral-White

Parameter	Symbol		Value		Unit
	Symbol	Min	Тур	Max	Umt
Luminous Flux [1]	Φ V ^[2]	30	~	90	lm
Correlated Color Temperature [3]	CCT	3500	~	4500	K
Forward Voltage [4]	VF	3.0	~	3.8	V
View Angle	201/2	120			deg.
Thermal Resistance ^[5]	Rθ ј-в	8			°C/W
Thermal Resistance ^[6]	R θ j-c	6.5		°C/W	

2-1 Electrical-Optical Characteristics at IF=350mA, TA=25 $^\circ\!\!\mathbb{C}$

2-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	IF	350	mA
Power Dissipation	Pd	1.05~1.33	W
Junction Temperature	Tj	125	°C
Operating Temperature	Topr	-30~+85	°C
Storage Temperature	Tstg	-40~+120	°C
ESD Sensitivity [7]	~	±2,000V HBM	~

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] $\phi \mathbf{v}$ is the total luminous flux output as measured with an integrated sphere.
- [3] Correlated Color Temperatures is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ testing tolerance
- [4] A tolerance of ± 0.06 V on forward voltage measurements
- [5],[6] R θ J-B is measured with a SSC metal core pcb.(25°C \leq TJ \leq 110°C) R θ J-C is measured with only emitter.. (25°C \leq TJ \leq 110°C)

Break voltage of Metal PCB is 6.5kVAC

[7]It is included the zener chip to protect the product from ESD.

-----Caution-----

3 Warm-White

Parameter	Symbol		Value		Unit
	Symbol	Min	Тур	Max	Umt
Luminous Flux [1]	Φ V ^[2]	40	~	100	lm
Correlated Color Temperature [3]	CCT	2400	~	3300	K
Forward Voltage [4]	VF	3.0	~	3.8	V
View Angle	201/2	120			deg.
Thermal Resistance [5]	Rθ ј-в	8			°C/W
Thermal Resistance [6]	R θ j-c	6.5		°C/W	

3-1 Electrical-Optical Characteristics at IF=350mA, TA=25 $^{\circ}$ C

3-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	IF	350	mA
Power Dissipation	PD	1.05~1.33	W
Junction Temperature	Tj	125	°C
Operating Temperature	Topr	-30~+85	°C
Storage Temperature	Tstg	-40~+120	°C
ESD Sensitivity [7]	~	±2,000V HBM	~

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] $\phi \mathbf{v}$ is the total luminous flux output as measured with an integrated sphere.
- [3] Correlated Color Temperatures is derived from the CIE 1931 Chromaticity diagram. CCT $\pm 5\%$ testing tolerance
- [4] A tolerance of $\pm 0.06V$ on forward voltage measurements
- [5],[6] R θ J-B is measured with a SSC metal core pcb.(25 °C \leq TJ \leq 110 °C)
 - R θ J-C is measured with only emitter.. (25 °C \leq TJ \leq 110 °C)

Break voltage of Metal PCB is 6.5kVAC

[7]It is included the zener chip to protect the product from ESD.

-----Caution-----

4、Blue

Parameter	Symbol		Value		Unit
i ai ailletei	Symbol	Min	Тур	Max	Umt
Luminous Flux [1]	↓ v ^[2]	10	16	25	lm
Dominant Wavelength [3]	λd	455	465	475	nm
Forward Voltage ^[4]	VF	3.0	3.5	3.8	V
View Angle	201/2	125		deg.	
Thermal Resistance ^[5]	Rθ ј-в	7.8		°C/W	
Thermal Resistance [6]	R θ ј-с	6		°C/W	

4-1 Electrical-Optical Characteristics at IF=350mA, TA=25 $^\circ\!\!\mathbb{C}$

4-2 Absolute Maximum Ratings

Parameter	Symbol	Symbol Value	
Forward Current	IF	350	mA
Power Dissipation	Pd	1.05~1.33	W
Junction Temperature	Tj	125	°C
Operating Temperature	Topr	-30~+85	°C
Storage Temperature	Tstg	-40~+120	°C
ESD Sensitivity [7]	~	±2,000V HBM	~

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] $\phi \mathbf{v}$ is the total luminous flux output as measured with an integrated sphere.
- [3] Dominant wavelength is derived from the CIE 1931 Chromaticity diagram.

A tolerance of ± 0.5 nm for dominant wavelength

- [4] A tolerance of ± 0.06 V on forward voltage measurements
- [5],[6] R θ J-B is measured with a SSC metal core pcb.(25°C \leq TJ \leq 110°C)
 - R θ J-C is measured with only emitter.. (25 °C \leq TJ \leq 110 °C)

Break voltage of Metal PCB is 6.5kVAC

[7]It is included the zener chip to protect the product from ESD.

-----Caution-----

- 1. Please do not drive at rated current more than 5sec. Without proper hear sink
- 2, Blue power light sources represented here are IEC825 Class 2 for eyes safety

5, Green

Parameter	Symbol		Value		Unit
i ai ailetti	Symbol Min	Min	Тур	Max	Umt
Luminous Flux [1]	φ ν [2]	50	60	80	lm
Dominant Wavelength [3]	λd	515	525	535	nm
Forward Voltage ^[4]	VF	3.2	3.5	3.8	V
View Angle	201/2	125		deg.	
Thermal Resistance ^[5]	Rθ ј-в	7.8		°C/W	
Thermal Resistance [6]	R θ ј-с	6		°C/W	

5-1 Electrical-Optical Characteristics at IF=350mA, TA=25 $^\circ\!\mathrm{C}$

5-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	IF	350	mA
Power Dissipation	Pd	1.12~1.33	W
Junction Temperature	Tj	125	°C
Operating Temperature	Topr	-30~+85	°C
Storage Temperature	Tstg	-40~+120	°C
ESD Sensitivity [7]	~	±2,000V HBM	~

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] $\phi \mathbf{v}$ is the total luminous flux output as measured with an integrated sphere.
- [3] Dominant wavelength is derived from the CIE 1931 Chromaticity diagram. A tolerance of ± 0.5 nm for dominant wavelength
- [4] A tolerance of ± 0.06 V on forward voltage measurements
- [5],[6] R θ J-B is measured with a SSC metal core pcb.(25°C \leq TJ \leq 110°C)
 - R0 J-c is measured with only emitter.. (25 $^\circ C \! \ll \! TJ \! \leqslant \! 110 \,^\circ C$)

Break voltage of Metal PCB is 6.5kVAC

[7]It is included the zener chip to protect the product from ESD.

-----Caution-----

6, Red

Parameter	Symbol		Value		Unit
r ai aineter	Symbol	Symbol Min	Тур	Max	Umt
Luminous Flux [1]	φ ν ^[2]	30	~	50	lm
Dominant Wavelength [3]	λd	615	625	635	nm
Forward Voltage ^[4]	VF	2.0	2.3	2.9	V
View Angle	201/2	130		deg.	
Thermal Resistance ^[5]	Rθ ј-в	7		°C/W	
Thermal Resistance [6]	R θ ј-с	5.8		°C/W	

6-1 Electrical-Optical Characteristics at IF=400mA, TA=25 $^\circ\!\mathrm{C}$

6-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	IF	400	mA
Power Dissipation	Pd	0.80~1.16	W
Junction Temperature	Tj	125	°C
Operating Temperature	Topr	-30~+85	°C
Storage Temperature	Tstg	-40~+120	°C
ESD Sensitivity [7]	~	±2,500V HBM	~

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] $\phi \mathbf{v}$ is the total luminous flux output as measured with an integrated sphere.
- [3] Dominant wavelength is derived from the CIE 1931 Chromaticity diagram. A tolerance of ± 0.5 nm for dominant wavelength
- [4] A tolerance of ± 0.06 V on forward voltage measurements
- [5],[6] R θ J-B is measured with a SSC metal core pcb.(25 °C \leq TJ \leq 110 °C)
 - R θ J-c is measured with only emitter.. (25 °C \leq TJ \leq 110 °C)

Break voltage of Metal PCB is 6.5kVAC

[7]It is included the zener chip to protect the product from ESD.

-----Caution-----

7、Yellow

Parameter	Symbol	Value		Unit	
		Min	Тур	Max	Umt
Luminous Flux [1]	↓ v ^[2]	30	~	50	lm
Dominant Wavelength [3]	λd	585	580	595	nm
Forward Voltage ^[4]	VF	2.0	2.3	2.9	V
View Angle	201/2	130		deg.	
Thermal Resistance ^[5]	Rθ ј-в	7		°C/W	
Thermal Resistance [6]	R θ ј-с	5.8		°C/W	

7-1 Electrical-Optical Characteristics at IF=400mA, TA=25 $^\circ\!\!\mathbb{C}$

7-2 Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	IF	400	mA
Power Dissipation	Pd	0.80~1.16	W
Junction Temperature	Tj	125	°C
Operating Temperature	Topr	-30~+85	°C
Storage Temperature	Tstg	-40~+120	°C
ESD Sensitivity [7]	~	±2,500V HBM	~

*Notes:

- [1] SSC maintains a tolerance of $\pm 10\%$ on flux and power measurements.
- [2] $\phi \mathbf{v}$ is the total luminous flux output as measured with an integrated sphere.
- [3] Dominant wavelength is derived from the CIE 1931 Chromaticity diagram.

A tolerance of ± 0.5 nm for dominant wavelength

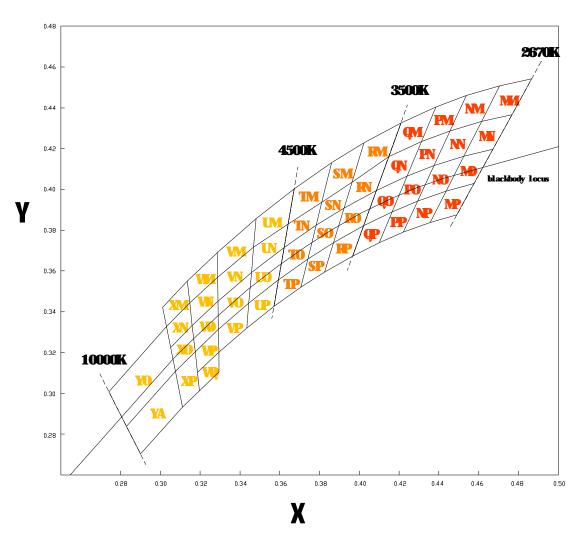
- [4] A tolerance of ± 0.06 V on forward voltage measurements
- [5] ,[6] R θ J-B is measured with a SSC metal core pcb.(25 °C \leq TJ \leq 110 °C)
 - $R\theta$ J-c is measured with only emitter.. (25 $^\circ C \! \ll \! TJ \! \ll \! 110 \,^\circ C$)

Break voltage of Metal PCB is 6.5kVAC

[7]It is included the zener chip to protect the product from ESD.

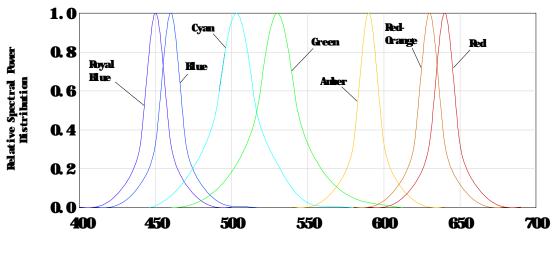
-----Caution-----

White Binning Informatio



White Hinning Structure

Other Color Separation Standards



Wivelength(nn)

Color emitting		Wavelength (nm)	Lumi nousFl ux (1m)	Drive Voltage(v)
Blue	spectrum	455-475	10-25	3.0-3.8
	span	5	5	0.4
Green	spectrum	515-535	50-80	3.0-3.8
	span	3	10	0.4
Red	spectrum	615-635	30-50	2.0-2.9
	span	5	10	0.3
Yellow	spectrum	585-595	30-50	2.0-2.9
	span	3	10	0.3